



**THE DATASHEET OF
AOZ8222DI-05**



General Description

The AOZ8222DI-05 is a two-line transient voltage suppressor diode designed to protect voltage sensitive electronics from high transient conditions and ESD.

This device incorporates two TVS diodes in an ultra-small DFN 1.0 x 0.6 package. During transient conditions, the TVS diodes direct the transient to ground. The AOZ8222DI-05 may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (± 15 kV air, ± 8 kV contact discharge).

The AOZ8222DI-05 comes in an RoHS compliant 3-lead DFN package and is rated over a -40 °C to $+85$ °C ambient temperature range.

The ultra-small 1.0 mm x 0.6 mm x 0.5 mm DFN package makes it ideal for applications where PCB space is a premium. The small size and high ESD protection makes it ideal for protecting voltage sensitive electronics from high transient conditions and ESD.

Features

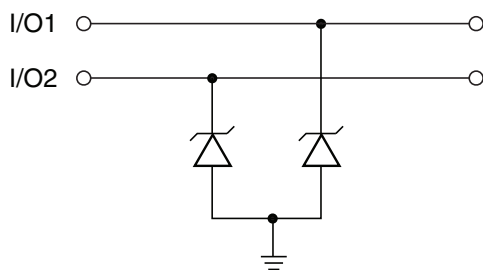
- ESD protection for high-speed data lines:
 - Exceeds IEC 61000-4-2 (ESD): ± 20 kV (air), ± 20 kV (contact)
 - Human Body Model (HBM) ± 30 kV
- Small package saves board space
- Low insertion loss
- Low clamping voltage
- Low operating voltage: 5 V

Applications

- Portable handheld devices
- Keypads, data lines, buttons
- Notebook computers
- Digital Cameras
- Portable GPS
- MP3 players

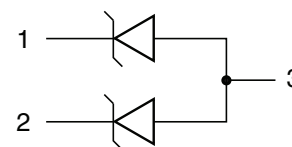


Typical Application



Unidirection Protection of Two Line

Pin Configuration



Ordering Information

Part Number	Ambient Temperature Range	Package	Environmental
AOZ8222DI-05	-40 °C to +85 °C	DFN 1.0 x 0.6-3L	Green Product



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit www.aosmd.com/media/AOSGreenPolicy.pdf for additional information.

Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	AOZ8222DI-05DI-05
Peak Pulse Current, $t_p = 8/20 \mu s$	5.5 A
Peak Pulse Power, $t_p = 8/20 \mu s$	50 W
Storage Temperature (T_S)	-65 °C to +150 °C
ESD Rating per IEC61000-4-2, Contact ⁽¹⁾	± 20 kV
ESD Rating per IEC61000-4-2, Air ⁽¹⁾	± 20 kV
ESD Rating per Human Body Model ⁽²⁾	± 30 kV

Notes:

- IEC 61000-4-2 discharge with $C_{Discharge} = 150 \text{ pF}$, $R_{Discharge} = 330 \Omega$.
- Human Body Discharge per MIL-STD-883, Method 3015 $C_{Discharge} = 100 \text{ pF}$, $R_{Discharge} = 1.5 \text{ k}\Omega$.

Maximum Operating Ratings

Parameter	Rating
Junction Temperature (T_J)	-40 °C to +125 °C

Electrical Characteristics

$T_A = 25\text{ }^\circ\text{C}$ unless otherwise specified.

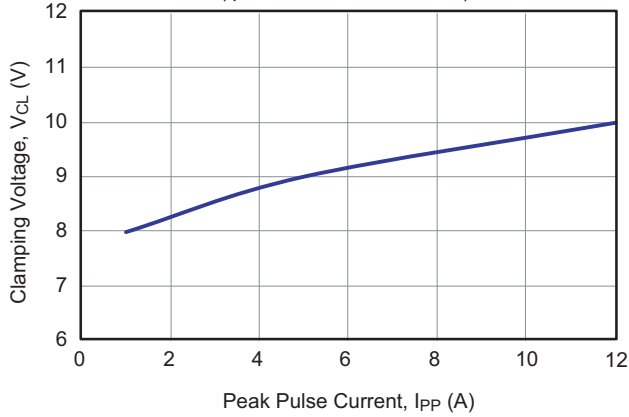
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{RWM}	Reverse Working Voltage	Between I/O and VN ⁽³⁾			5.0	V
V_{BR}	Reverse Breakdown Voltage	$I_T = 1\text{ mA}$, between I/O and VN ⁽⁴⁾	6.0			V
I_R	Reverse Leakage Current	$V_{RWM} = 5\text{ V}$, between I/O and VN			1	μA
V_F	Diode Forward Voltage	$I_F = 10\text{ mA}$	0.6	0.7	0.9	V
V_{CL}	Channel Clamp Voltage Positive Transients Negative Transients	$I_{PP} = 1\text{ A}$, $t_p = 100\text{ ns}$, any I/O pin to Ground ⁽⁵⁾⁽⁶⁾			8.0 -2.0	V V
	Channel Clamp Voltage Positive Transients Negative Transients	$I_{PP} = 5\text{ A}$, $t_p = 100\text{ ns}$, any I/O pin to Ground ⁽⁵⁾⁽⁶⁾			9.0 -5.0	V V
	Channel Clamp Voltage Positive Transients Negative Transients	$I_{PP} = 12\text{ A}$, $t_p = 100\text{ ns}$, any I/O pin to Ground ⁽⁵⁾⁽⁶⁾			10.0 -10.0	V V
C_J	Channel Input Capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$, between I/O pins ⁽⁶⁾		8	9	pF
		$V_R = 0\text{ V}$, $f = 1\text{ MHz}$, any I/O pin to Ground ⁽⁶⁾		15	18	pF

Notes:

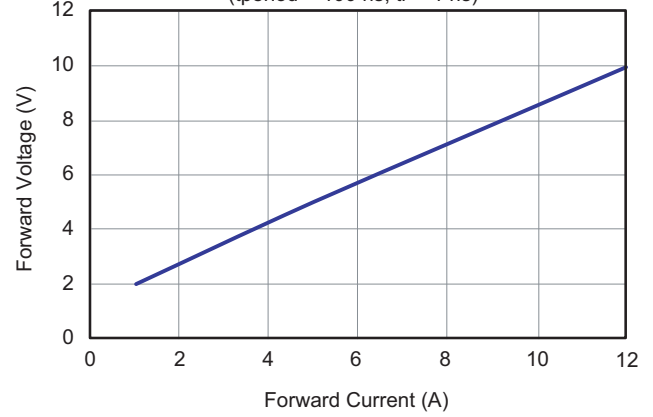
3. The working peak reverse voltage, V_{RWM} , should be equal to or greater than the DC or continuous peak operating voltage level.
4. V_{BR} is measured at the pulse test current I_T .
5. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.
6. Guaranteed by design and characterization.

Typical Performance Characteristics

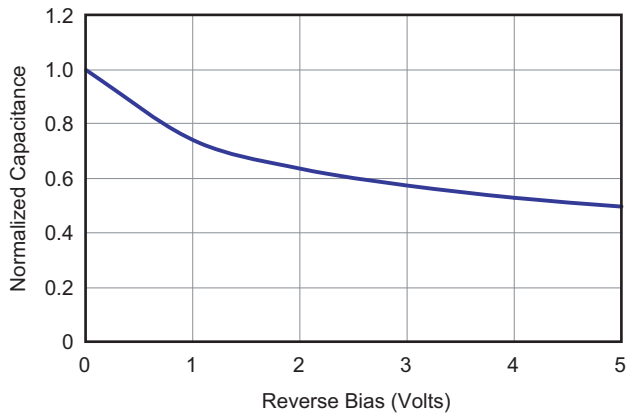
Clamping Voltage vs. Peak Pulse Current
(tperiod = 100 ns, tr = 1 ns)



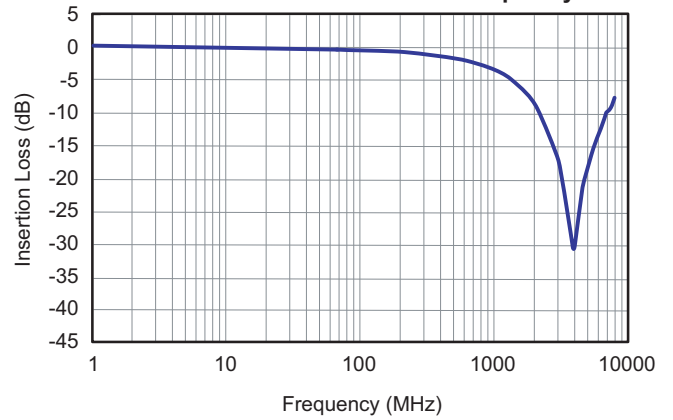
Forward Voltage vs. Forward Current
(tperiod = 100 ns, tr = 1 ns)



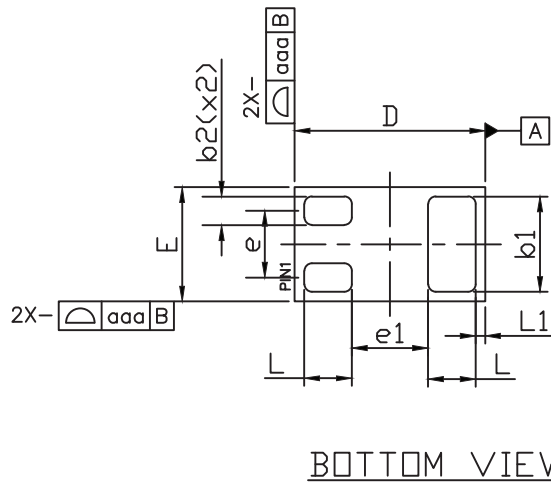
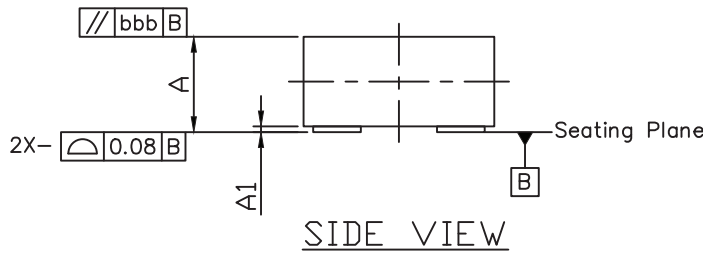
Capacitance vs. Reverse Bias



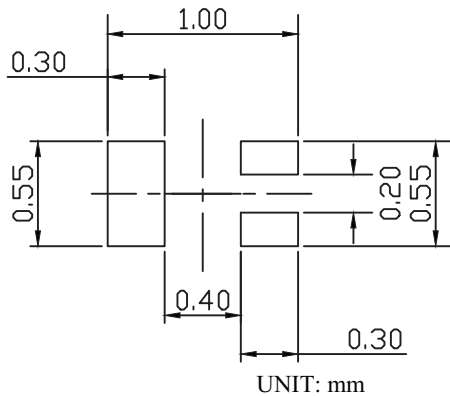
I/O – Gnd Insertion Loss vs. Frequency



Package Dimensions, DFN1.0x0.6



RECOMMENDED LAND PATTERN



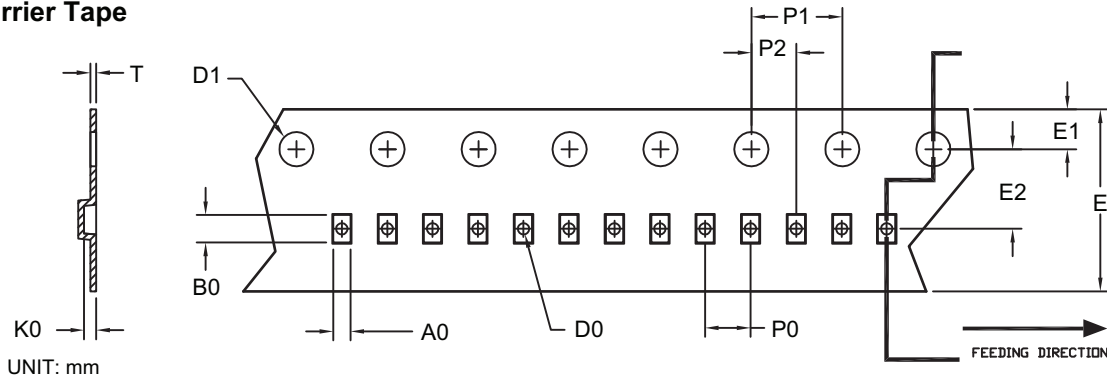
SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.47	0.52	0.55	0.019	0.020	0.022
A1	0.00	0.03	0.05	0.000	0.001	0.002
b1	0.45	0.50	0.55	0.018	0.020	0.022
b2	0.10	0.15	0.20	0.004	0.006	0.008
D	0.95	1.00	1.05	0.037	0.039	0.041
E	0.55	0.60	0.65	0.022	0.024	0.026
e	---	0.35	---	---	0.014	---
e1	---	0.40	---	---	0.016	---
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	---	0.05	---	---	0.002	---
aaa	0.15			0.006		
bbb	0.05			0.002		

NOTE

1. ALL DIMENSION ARE IN MILLIMETERS.ANGLES ARE IN DEGREES.
2. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.

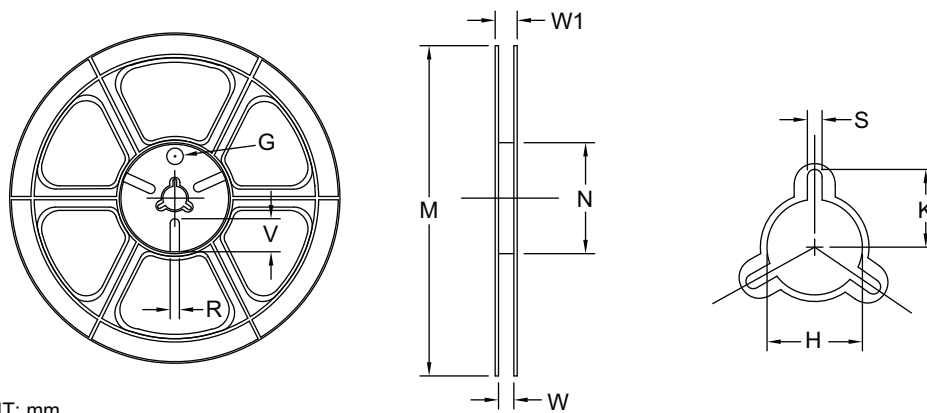
Tape and Reel Dimensions, DFN1.0x0.6

Carrier Tape



Option	Package	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
A	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.69 ±0.05	1.19 ±0.05	0.66 ±0.05	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.05	4.00 ±0.10	2.00 ±0.05	0.23 ±0.02
B	DFN 1.0x0.6/ DFN 1.0x0.6A (8 mm)	0.65 ±0.04	1.05 ±0.04	0.61 ±0.04	0.40 ±0.05	1.50 ±0.10	8.00 +0.3/-0.1	1.75 ±0.10	3.50 ±0.05	2.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.20 ±0.05

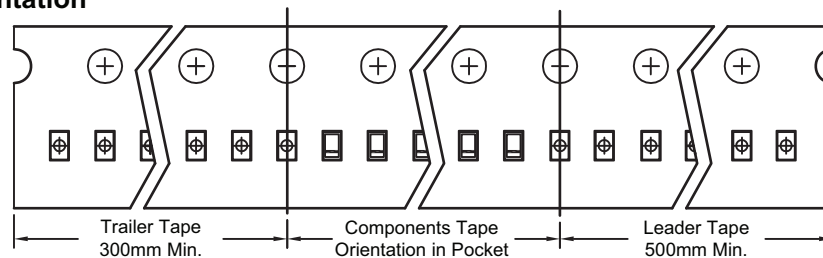
Reel



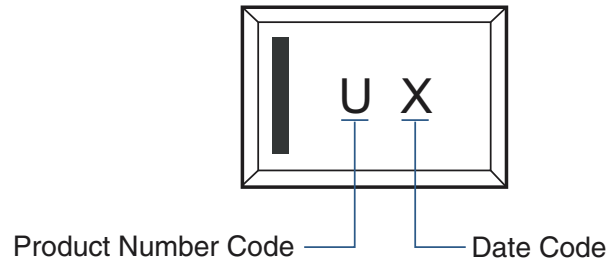
Tape Size	Reel Size	M	N	W	W1	H	K	S	G	R	V
8mm	ø178	ø178 ±0.5	ø55 ±1	8.4 +1.5/-0	Max. 14.4	ø13.0 ±0.5	Max. 10.1	2.0 ±0.5	N/A	N/A	N/A

Leader / Trailer & Orientation

TVS
Unit Per Reel:
10000pcs



Part Marking



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